



MADE EASY

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ESE 2025 : Mains Test Series

UPSC ENGINEERING SERVICES EXAMINATION

Electronics & Telecommunication Engineering Test-7 : Full Syllabus Test (Paper-I)

Name :

Roll No :

Test Centres

Delhi ☒ Bhopal ☐ Jaipur ☐ Pune ☐
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Student's Signature

Instructions for Candidates

1. Do furnish the appropriate details in the answer sheet (viz. Name & Roll No).
2. There are Eight questions divided in TWO sections.
3. Candidate has to attempt FIVE questions in all in English only.
4. Question no. 1 and 5 are compulsory and out of the remaining THREE are to be attempted choosing at least ONE question from each section.
5. Use only black/blue pen.
6. The space limit for every part of the question is specified in this Question Cum Answer Booklet. Candidate should write the answer in the space provided.
7. Any page or portion of the page left blank in the Question Cum Answer Booklet must be clearly struck off.
8. There are few rough work sheets at the end of this booklet. Strike off these pages after completion of the examination.

FOR OFFICE USE

Question No.	Marks Obtained
Section-A	
Q.1	34
Q.2	50
Q.3	/
Q.4	39
Section-B	
Q.5	44
Q.6	/
Q.7	/
Q.8	28
Total Marks Obtained	195

Signature of Evaluator

Cross Checked by

Ch. R. Singh

• Good attempt.

IMPORTANT INSTRUCTIONS

CANDIDATES SHOULD READ THE UNDERMENTIONED INSTRUCTIONS CAREFULLY. VIOLATION OF ANY OF THE INSTRUCTIONS MAY LEAD TO PENALTY.

DONT'S

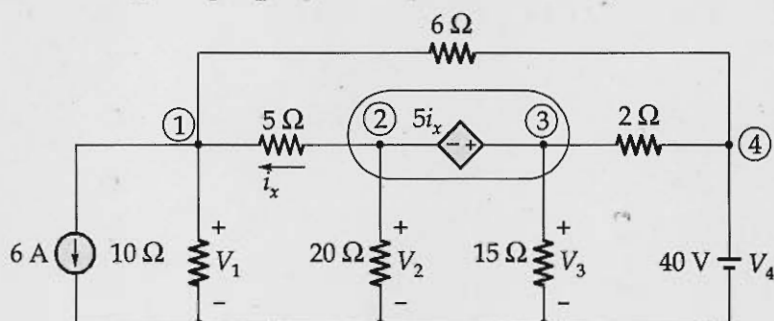
1. Do not write your name or registration number anywhere inside this Question-cum-Answer Booklet (QCAB).
2. Do not write anything other than the actual answers to the questions anywhere inside your QCAB.
3. Do not tear off any leaves from your QCAB, if you find any page missing do not fail to notify the supervisor/invigilator.
4. Do not leave behind your QCAB on your table unattended, it should be handed over to the invigilator after conclusion of the exam.

DO'S

1. Read the Instructions on the cover page and strictly follow them.
2. Write your registration number and other particulars, in the space provided on the cover of QCAB.
3. Write legibly and neatly.
4. For rough notes or calculation, the last two blank pages of this booklet should be used. The rough notes should be crossed through afterwards.
5. If you wish to cancel any work, draw your pen through it or write "Cancelled" across it, otherwise it may be evaluated.
6. Handover your QCAB personally to the invigilator before leaving the examination hall.

Section A

Q.1 (a) Find the node voltages V_1 , V_2 , V_3 and V_4 in the circuit given below:



[12 marks]

(a) from circuit

$$V_4 = 40 \text{ V}$$

$$V_3 - V_2 = V_2 - V_1$$

$$V_1 - 2V_2 + V_3 = 0 \quad \text{--- (6)}$$

statement: super nodal analysis

is applicable whenever

there is a ~~independent~~ ^{ideal} voltage source b/w two nodes.

Simply from (3),

$$V_1 \left(\frac{1}{10} + \frac{1}{5} + \frac{1}{15} \right) + V_2 \left(\frac{1}{20} + \frac{1}{5} \right) + V_3 \left(\frac{1}{15} + \frac{1}{2} \right) = \frac{40}{40} \quad \text{--- (7)}$$

By KCL,

$$\frac{V_1}{10} + 6 + \frac{V_1 - 40}{6} = i_x \quad \text{--- (1)}$$

$$i_x = \frac{V_2 - V_1}{5} \quad \text{--- (2)}$$

By super node technique,

$$\frac{V_2}{20} + \frac{V_2 - V_1}{5} + \frac{V_3}{15} + \frac{V_3 - 40}{2} = 0 \quad \text{--- (3)}$$

$$4V_3 - V_2 = 5i_x \quad \text{--- (4)}$$

Put (2) in (1) & (4).

$$\frac{V_1}{10} + 6 + \frac{V_1}{6} - \frac{40}{6} = \frac{V_2 - V_1}{5}$$

$$V_1 \left(\frac{1}{10} + \frac{1}{6} + \frac{1}{5} \right) - \frac{V_2}{5} = \frac{40}{6} + 6 \quad \text{--- (5)}$$

So from (5), (6) & (7)

on solving,

$$V_1 = 43.70 \text{ V}$$

$$V_2 = 38.68 \text{ V}$$

$$V_3 = 33.65 \text{ V}$$

$$V_4 = 40 \text{ V}$$

Q.1 (b) Implement a Full subtractor with two 4×1 multiplexers.

[12 marks]

Q1. (b) Full Subtractor configuration

Truth Table:

A	B	C _{in}	B	D
0	0	0	0	0
0	0	1	1	1
0	1	0	1	1
0	1	1	1	0
1	0	0	0	1
1	0	1	0	0
1	1	0	0	0
1	1	1	1	1

where (B): Borrow
(D): Difference.

K-map for (B):

BC	00	01	11	10
A	0	1	1	1
1	4	5	7	6

$$B = \bar{A}C + \bar{A}B + BC$$

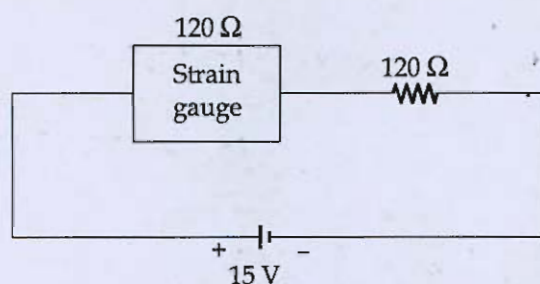
K-map for (D):

BC	00	01	11	10
A	0	1	1	3
1	4	5	7	6

$$D = A \oplus B \oplus C$$

10

- 2.1 (c) A strain gauge having a resistance of $120\ \Omega$ and a gauge factor of 2 is connected in series with a ballast resistance of $120\ \Omega$ across 15 V supply as shown below:



Calculate the difference between the output voltage (voltage across the strain gauge) with no stress applied and with a stress of 150 MN/m^2 . The modulus of elasticity of the material undergoing strain is 200 GN/m^2 .

[12 marks]

2.1 (c). when no stress applied

$$R = R_0 = 120\ \Omega$$

$$\therefore V_0 = \text{voltage across gauge} = \frac{15 \times 120}{240} = 7.5\text{ V}$$

when stress applied,

$$\text{we know, } \frac{\Delta R}{R} = (1 + 2\gamma) \frac{\Delta L}{L}$$

$$\frac{\text{stress}}{\text{strain}} = \text{mod. of elasticity}$$

$$\frac{150 \times 10^6}{200 \times 10^9} = \text{strain}$$

$$\frac{3}{4} \times 10^{-3} = \text{strain}$$

$$\therefore \frac{OR}{R} = (1 + 2(2)) \times \frac{3}{4} \times 10^{-3}$$

$$OR = 5 \times \frac{3}{4} \times 10^{-3}$$

$$OR = +3.75 \times 10^{-3}$$

$$\therefore V_o' = 15 \times \frac{123.75}{120 + 123.75}$$

$$V_o' = 7.61 \text{ V}$$

difference in output voltage

$$\Delta V = 7.61 - 7.5$$

$$\Delta V = 0.115 \text{ V}$$

1 (d) A typical paper clip weighs 0.59 g. Assume that it is made from BCC iron. Calculate:

- (i) The number of unit cells.
(ii) The number of iron atoms in the paper clip.

(Assume for BCC iron, lattice parameter $a_0 = 2.866 \times 10^{-8}$ cm, atomic mass = 55.847 g/mol, Density $\rho = 7.87$ g/cm³)

[12 marks]

21. (a) Given:-

• BCC Iron

$$\circ \text{ mass} = 55.847 \text{ g/mol}$$

• weight (A) = 0.59 g

$$\circ \rho = 7.87 \text{ g/cm}^3$$

$$\circ a = 2.866 \times 10^{-8} \text{ cm}$$

Statement:- we know density $(\rho) = \frac{n \cdot A}{N_A \cdot V_c}$

where $[V_c : \text{Volume}]$.

from above,

$$7.87 = \frac{n \times 55.847}{6.023 \times 10^{23} \times (2.866 \times 10^{-8})^3}$$

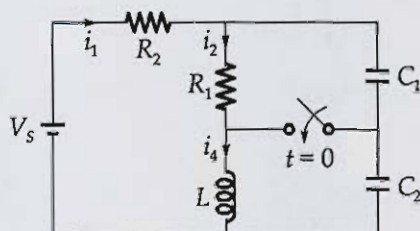
$$n = \frac{7.87 \times 6.023 \times 10^{23} \times (2.866 \times 10^{-8})^3}{55.847}$$

on solving,

$$n = 2.02$$

$$\boxed{n = 2}$$

- Q.1 (e) Determine the current i_1 , i_2 and i_4 at $t = 0^+$ for the circuit given below. Assume that the voltage source is applied at $t = -\infty$.



[12 marks]

- Q.10 (e) for the above network,
consider time instance ($t < 0^-$),

Statement: for DC source,

$$DC \rightarrow L \rightarrow S/C$$

$$DC \rightarrow C \rightarrow O/C$$

L : Inductor

C : Capacitor

$$i_L(0^-) = \frac{V_s}{R_1 + R_2} \quad \text{--- (1)}$$

$$\text{By KVL, } V_{C_1}(0^-) = i_2 \times R_1$$

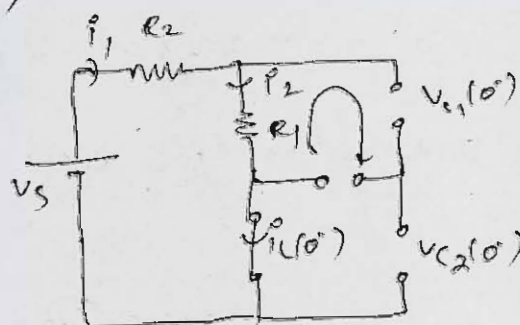
$$V_{C_2}(0^-) = i_2 \times R_1$$

$$\text{where } i_2 = i_L(0^-)$$

$$V_{C_1}(0^-) = \frac{V_s R_1}{R_1 + R_2}$$

$$V_{C_2}(0^-) = \frac{V_s R_1}{R_1 + R_2}$$

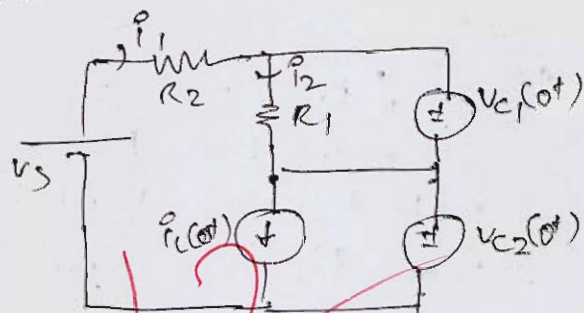
we know inductor does not allow sudden change in current & capacitor, sudden change in voltage.



$$p.o. \quad i_L(0) = i_L(0^+)$$

$$V_C(0^-) = V_C(0^+)$$

at $t = 0^+$, circuit is,



$$p.o. \quad i_L(0^+) = i_L(0^-)$$

$$i_L(0^+) = \frac{V_S}{R_1 + R_2} \quad \text{--- (1)}$$

$$i_2(0^+) = \frac{V_C(0^+)}{R_1} = \frac{V_S}{R_1 + R_2} \quad \text{--- (2)}$$

By KVL

$$-V_S + i_1 R_2 + V_{C1} + V_{C2} = 0$$

$$i_1 = \frac{V_S - V_{C1} - V_{C2}}{R_2}$$

$$i_1(0^+) = \frac{V_S}{R_2} \left[1 - \frac{2R_1}{R_1 + R_2} \right] \quad \text{--- (3)}$$

Conclusion: Hence (1), (2), (3) represents respective answers.

2.2 (a) (i) An assembly line has 3 safe sensors and one emergency shutdown switch. The line should keep moving unless any of the following conditions arise:

1. If the emergency switch is pressed.
2. If the sensor 1 and sensor 2 are activated at the same time.
3. If sensor 2 and sensor 3 are activated at the same time.
4. If all the sensors are activated at the same time.

Design a combinational circuit for above case using only two input NAND gates.

(ii) In a particular design which uses 5 bits for integral part and 7 bits for fractional part, the result of some operation is 7B8 Hex. Find the corresponding decimal equivalent.

[15 + 5 marks]

2.2) (a) (i) let the sensors be A, B, C.

and emergency shutdown switch = D.

let the output logic, Y

$Y = 0$, machine working

$Y = 1$, machine stops.

A	B	C	D	Y
0	0	0	0	0
0	0	0	1	1
0	0	1	0	0
0	0	1	1	1
0	1	0	0	0
0	1	0	1	1
0	1	1	0	1
0	1	1	1	1
1	0	0	0	0
1	0	0	1	1
1	0	1	0	0
1	0	1	1	1
1	1	0	0	1
1	1	0	1	1
1	1	1	0	1
1	1	1	1	1

logic for Y using

K-map:-

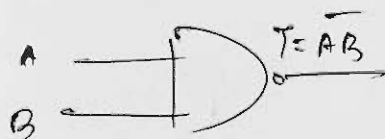
AB \ CD	CD			
	00	01	11	10
00	0	1 ₁	1 ₃	2
01	4	5	7	6
11	1 ₁₂	1 ₁₃	1 ₁₅	1 ₁₄
10	0	1 ₉	1 ₁₁	1 ₁₀

$$Y = D + AB + BC$$

So $Y = D + AB + BC$ is the

desired combination for my machine.

NAND representation

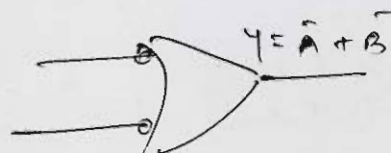


Representation (NAND)

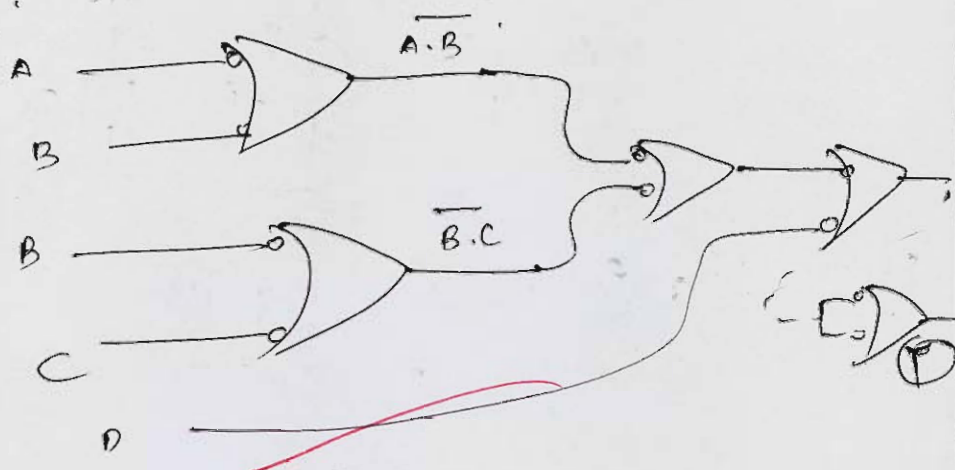
By de Morgan's law

$$\overline{A \cdot B} = \bar{A} + \bar{B}$$

∴ Representation (2) becomes:



∴ circuit:



Representation using NAND gates

2 (a) (ii) result = (7B8)_H

converting the above in binary form.

$$\text{Result} = (\underbrace{0111}_A \underbrace{1011000}_B)_2$$

Given: 5 bits for integral

7 bits for fractional.

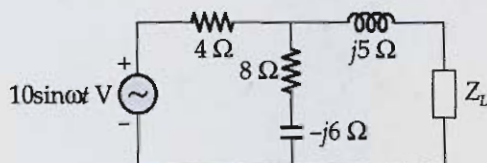
18

$$A = 01111 \rightarrow 15$$

$$B = 0111000 \rightarrow 0.4375$$

$$\therefore \text{In decimal } \boxed{(15.4375)_{10}} \text{ ans.}$$

- Q.2 (b) (i) Determine the load impedance Z_L that maximizes the average power drawn from the circuit shown below,



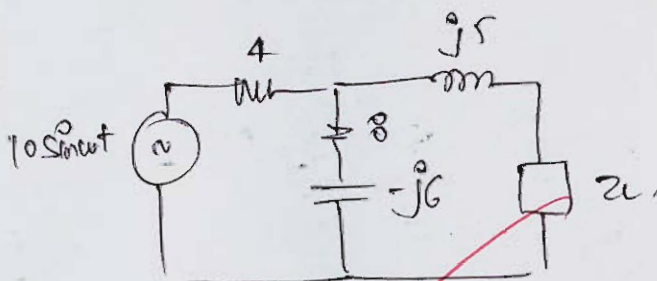
Find the maximum power drawn from the circuit.

- (ii) Derive the expression for the average power of an AC circuit.

[20 marks]

Q2

(b) (i) circuit:



Statement: ① for maximum power,

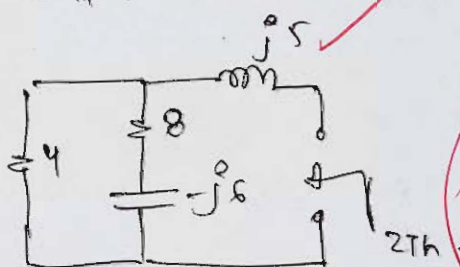
$$Z_L = Z_{Th}^*$$

② calculation of Z_{Th} .

Z_{Th} : Thevenin voltage.

- All sources deactivated

in circuit



$$Z_{Th} = 4 \parallel (8 - j6) + j5$$

$$= \frac{4 \times (8 - j6)}{12 - j6} + j5$$

$$\therefore Z_{Th} = 2.933 + j4.46$$

$$\therefore Z_L = Z_{Th}^*$$

$$Z_L = 2.933$$

$$-j4.46 \Omega$$

for $P_{\max}$:-

$$V_{Th} = 10 \angle 0^\circ \times \frac{(8 - j6)}{12 - j6}$$

$$V_{Th} = V_{oc}$$

$$V_{Th} = 7.453 \angle -10.30^\circ$$

$$\therefore P_{\max} = \frac{(7.453)^2}{4 \times 2.933}$$

$$P_{\max} = 4.73 \text{ watts}$$

(ii) In an AC circuit :-

Assume $v(t)$ & $i(t)$ are the applied voltage and current.

• The complex power is $S = V I^*$

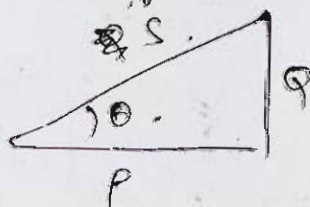
• Complex power represents the total power in the circuit.

The average power / real power is defined as

$$P_{\text{avg}} = \frac{1}{T} \text{Re} \{ V I^* \}$$

Since this is a real quantity.

using power triangle



$$\therefore \frac{P}{S} = \cos \phi$$

$$\therefore P = S \cos \phi$$

$$\therefore P_{\text{avg}} = V_{\text{RMS}} \times I_{\text{RMS}} \cos \phi$$

$$\& \text{ } Q \text{ (inductive) power} = V_{\text{RMS}} I_{\text{RMS}} \sin \phi$$

- Q.2 (c) (i) A long n -type semiconductor bar is placed along positive x -axis and is illuminated by a constant light source at one end (at $x = 0$). This illumination resulted in the generation of excess carriers at the surface (at $x = 0$) and these excess carriers are diffused into the bar. The variation of the minority carriers, in the bar along the positive x -axis, is given by,

$$p_n(x) = p_{n0} + p'_n e^{-\frac{x}{L_p}}; x > 0$$

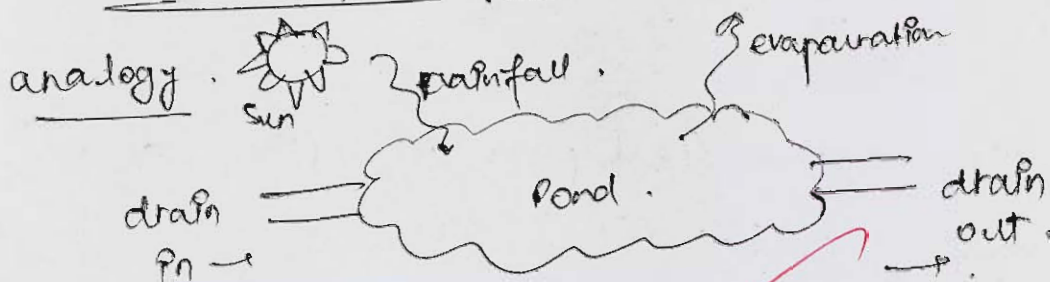
Prove that L_p is the average distance travelled by the diffusing carriers before they recombine.

- (ii) In an $n^+ - p - n^+$ transistor with uniform base doping, the neutral base width (that is, the undepleted portion of the base) is $1.2 \mu\text{m}$ when $V_{CB} = 5 \text{ V}$. The depletion layer of the collector-base junction extended into base region for this case is $0.3 \mu\text{m}$. Find the value of the collector-base voltage V_{CB} at which the entire base gets depleted. Neglect the built-in potential as well as the depletion layer width at the emitter-base junction.

[14 + 6 marks]

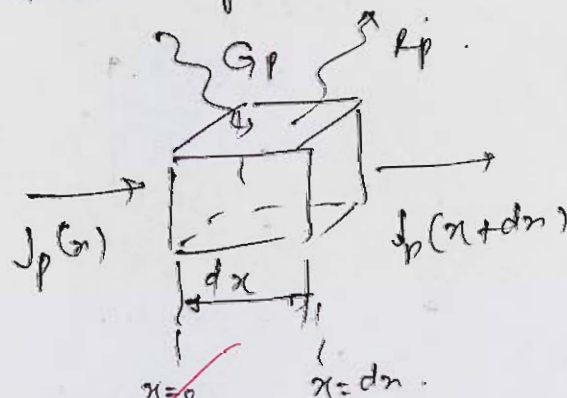
Q.2 (c) continuity equation for devices

(i)



In an ecosystem, multiple ~~process~~ (rainfall, evaporation, inlet & outlet of water) are happening.

In similar way, consider semiconductor sample.



diffusion density: $J_p(x)$

G_p : Generation $G_p(x) \cdot dx$ (in volume)

R_p : Recombination $R_p(x) \cdot dx$

where $R_p = \frac{dp}{dt}$

$$\therefore \frac{\partial p(x)}{\partial t} = \frac{dJ_p(x)}{dx} + G_p - R_p$$

By Taylor's expansion & simplification.

$$\left[\frac{\partial p}{\partial t} = \frac{1}{q} \frac{dJ_p(x)}{dx} + G_p - R_p \right] \quad \text{--- (1)}$$

① represents Continuity equation.

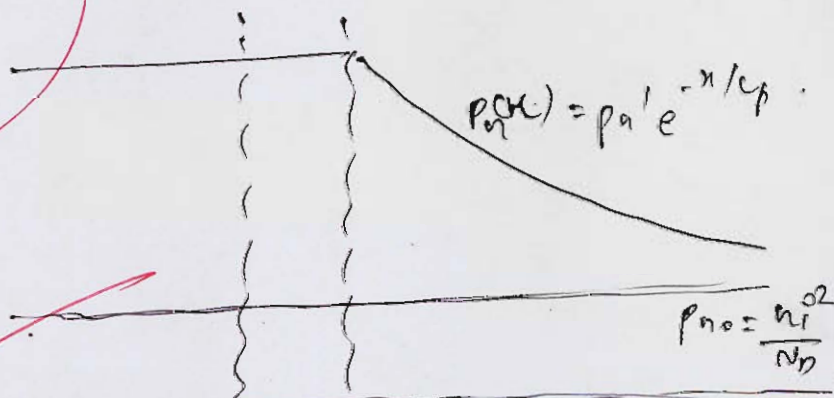
considering case of illumination & minority carrier diffusion in the sample.

$$\left[\frac{\partial p}{\partial t} = D_p \frac{d^2 p}{dx^2} + G_p - R_p \right] \quad \text{--- (2)}$$

on further

simplification,

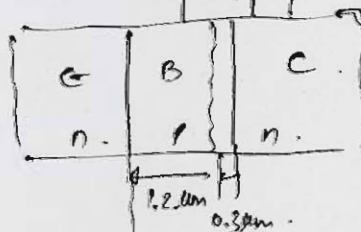
under constant
light source.



$$p(x) = p_{n0} + p_n' e^{-x/L_p}, \quad x > 0$$

(3)

sp. ch. V_{CB}



(ii)

Given, $w_B = 1.2 \text{ cm}$

$V_{CB} = 5 \text{ V}$

$$W = \sqrt{\frac{2\epsilon}{q} \left(\frac{1}{N_A} + \frac{1}{N_D} \right) (\phi_{G1} + V_{CB})}$$

for p-n⁺ junction.

$$N_D \gg N_A$$

$$\therefore W = \sqrt{\frac{2\epsilon}{q} \left(\frac{1}{N_A} \right) (\phi_{bi} + V_R)}$$

condⁿ - (2)

$$V_{CB} = \frac{(1.5 \times 10^{-6})^2 \times q \times N_A}{2\epsilon}$$

$$\frac{\omega^2 \times q \times N_A}{2\epsilon} = \phi_{bi} + V_R \quad \text{--- (1) from (3)}$$

 ϕ_{bi} neglected,

$$\frac{\omega^2 \times q \times N_A}{2\epsilon} = V_R \quad \text{--- (2)}$$

condⁿ - (1)

$$N_A = \frac{2\epsilon V_R}{\omega^2 \times q} \quad \text{--- (3)}$$

$$\text{here } \omega = (0.3 \times 10^{-6})$$

$$V_{CB} = \frac{(1.5 \times 10^{-6})^2 \times q \times 2\epsilon V_R}{\omega^2 \times q}$$

$$V_{CB} = \frac{(1.5 \times 10^{-6})^2}{(0.3 \times 10^{-6})^2} \times 5V$$

$$V_{CB} = 12.5V$$

Q.3 (a) A combinational circuit consists of inputs A, B, $S_1S_0 (= S)$ and an output F defined as follows:

- (i) If $(S = 0)$ then $F = \bar{A}$.
- (ii) If $(S = 1)$ then $F = A + B$.
- (iii) If $(S = 2)$ then $F = \bar{A} - B$.
- (iv) If $(S = 3)$ then $F = \bar{B}$.

Build the logic circuit with a full adder, a 4×1 multiplexer, XOR gate and an inverter.

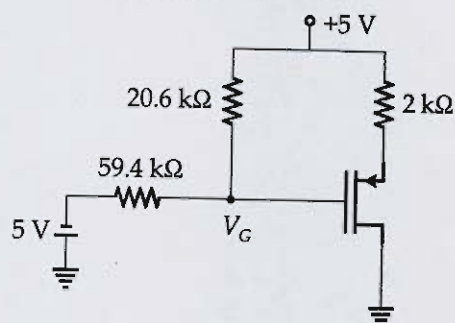
[20 marks]

Q.3 (a)

- Q.3 (b)** Consider a CsBr crystal (one Cs^+ – Br^- pair per unit cell) with a lattice parameter (a) of 0.430 nm. The electronic polarizability of Cs^+ and Br^- ions are $3.35 \times 10^{-40} \text{ F-m}^2$ and $4.5 \times 10^{-40} \text{ F-m}^2$ respectively, and the mean ionic polarizability per ion pair is $5.8 \times 10^{-40} \text{ F-m}^2$. Determine the value of dielectric constant at (i) very low frequencies and (ii) optical frequencies.

[20 marks]

Q.3 (c) Consider the circuit shown in the figure below:

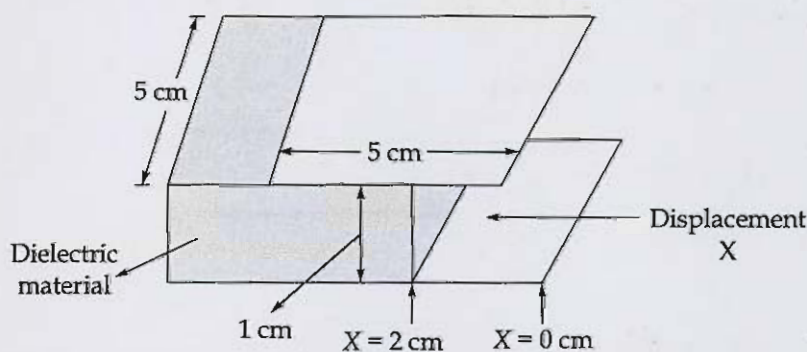


The transistor parameters are $V_{TP} = -1.5 \text{ V}$ and $\frac{\mu_p C_{ox} W}{2L} = 0.5 \text{ mA/V}^2$. Calculate:

- (i) The value of V_{SG} .
- (ii) The value of I_D .
- (iii) The value of V_{SD} .

[20 marks]

- Q.4 (a) (i) A $4\frac{1}{2}$ digit and a $3\frac{1}{2}$ digit voltmeter on 100 V and 10 V range respectively are used for voltage measurements.
- Find the resolution of each meter.
 - How would a voltage of 0.4312 V be displayed on these two meters?
- (ii) A capacitive transducer is used for the measurement of linear displacement, X as shown below:



The parallel plate has a dimension of $5.0\text{ cm} \times 5.0\text{ cm}$ and is separated by a distance of 1.0 cm . The space between the plates is filled with a dielectric material 1.0 cm thick, which has a dielectric constant of 4.0 . If dielectric constant for air is 1.0 , determine the value of the capacitance when X is equal to

- 0.0 cm
- 2.0 cm

[6 + 14 marks]

Q4 (a) (i) $4\frac{1}{2}$ & $3\frac{1}{2}$ DVM.

1. Resolution $(R) = \frac{1}{10^n}$.

∴ for $4\frac{1}{2}$ meter $(R) = \frac{1}{10^4} = 0.0001 \text{ V}$.

for $3\frac{1}{2}$ meter $(R) = \frac{1}{10^3} = 0.001 \text{ V}$.

2. given voltage 0.4312 V .

for $4\frac{1}{2}$ meter.

representation $\rightarrow 0.4312 \text{ V}$

for $3\frac{1}{2}$ meter

representation $\rightarrow 0.431 \text{ V}$.

Q4 (a) (ii) $\epsilon_r = 4.0$ (dielectric) $\epsilon_r = 1$ (air).

Area $= 5 \times 5 \text{ cm}$.

distance $= 1 \text{ cm}$.

we know:

$$C = \frac{\epsilon A}{d}$$

A: Area of plates

d: Separation b/w plates.

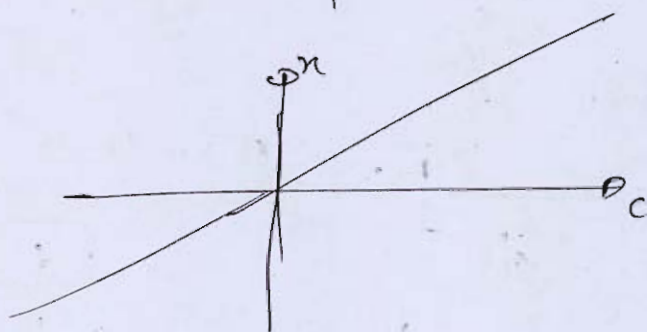
for $x = 0$ cm. (no displacement)

$$C = \frac{\epsilon_0 \times \epsilon_r \cdot A}{d}$$

$$C_0 = \frac{8.854 \times 10^{-12} \times 4 \times 2 \times 10^{-4}}{1 \times 10^{-2}}$$

$$C_0 = 8.85 \text{ pF}$$

In capacitive transducer, the capacitance and displacement have linear relationship.



$$C' = C_0 (1 + \frac{x}{d})$$

$$= 8.854 \times 2$$

$$C' = 1.77 \times 10^{-11} \text{ F}$$

- Q.4 (b) (i) Design RS flip-flop using NMOS.
- (ii) A 50 kVA, 2000/200V, 50 Hz transformer has an iron loss of 400 watt. The high voltage winding has a resistance of 0.6Ω and low voltage winding have a resistance of 0.006Ω . Calculate the efficiency if the load has power factor 0.8 (lagging) and operating at half-load.

[10 + 10 marks]

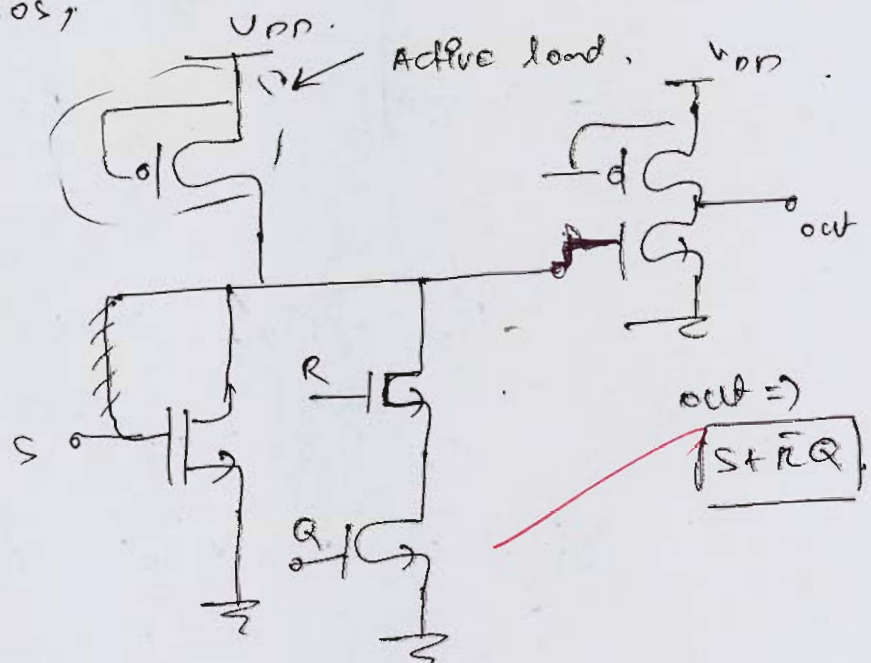
Q4) (6)(9)

The equation for next state
for rs flip flop,

$$Q^+ = S + \bar{R}Q$$

Q^+	S	R	Q
0	0	0	0
0	0	1	0
1	1	0	1
1	1	1	X

using NMOS,



design circuit
using NMOS

(b) (i) $S = 50 \text{ kVA}$ $P_f = 400 \text{ watts}$
 $\frac{2000}{200}$ $\cos \phi = 0.8 \text{ (lag)}$
 $f = 50 \text{ Hz}$

Statement:- $\eta = \frac{(kVA)_R \cos \phi \times \eta}{\eta \times (kVA)_R \cos \phi + \eta^2 \times (I_{FL}^2 \times R) + P_f}$

$R_{HW} = 0.6 \Omega$ $R_{LW} = 0.006 \Omega$

$S = 50 \text{ kVA}$

$I_{HW} = \frac{50 \times 10^3}{2000}$

$I_{LW} = \frac{50 \times 10^3}{200}$

$I_{HW} = 25 \text{ A}$

$I_{LW} = 250 \text{ A}$

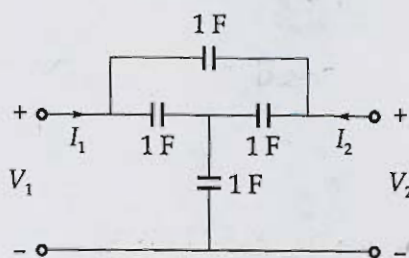
$(P_w)_{FL} = I_{FL}^2 \times R = 375 + 375$
 $= 750 \text{ watts}$

$\therefore \eta_{\frac{1}{2} FL} = \frac{50 \times 10^3 \times 0.8 \times \frac{1}{2}}{50 \times 10^3 \times 0.8 \times \frac{1}{2} + \frac{1}{4} \times 250 + 400}$

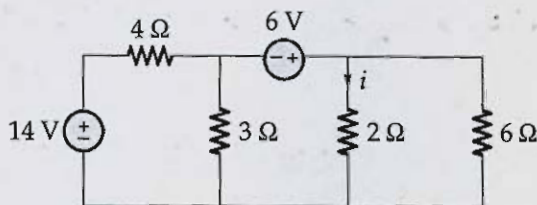
$\therefore \eta_{\frac{1}{2} FL} = 96.26 \%$

10

- Q.4 (c) (i) Determine y -parameters of circuit shown below in s -domain.



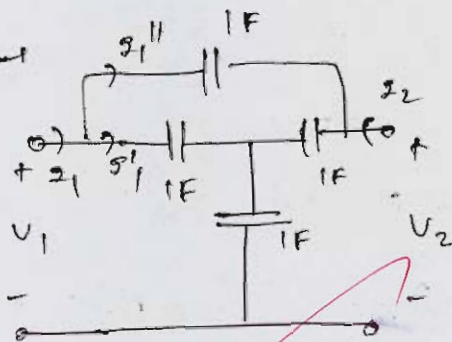
- (ii) For the circuit shown below,



find the current i .

[12 + 8 marks]

Q.4 (c) (i) Given circuit -



$$I_1 = I_1' + I_1''$$

∴ y -parameter applicable.

Network - 1

Calculation
[27]

$$Z_{11} = Z_a + Z_b \quad \left\{ \begin{array}{l} \text{from} \\ \text{T-model} \end{array} \right.$$

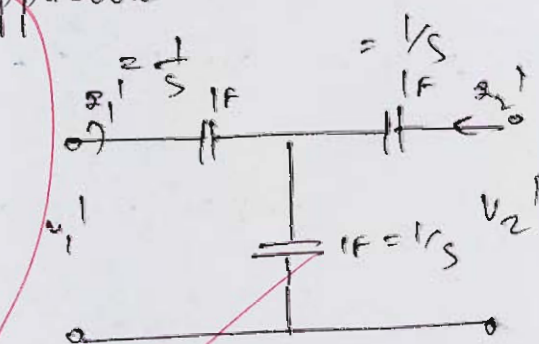
$$Z_{12} = Z_{21} = Z_b$$

$$Z_{22} = Z_b + Z_c$$

$$Z_{11} = \frac{2}{s}$$

$$Z_{12} = Z_{21} = \frac{1}{s}$$

$$Z_{22} = \frac{2}{s}$$



(in Laplace domain)

$$[y] = \begin{bmatrix} \frac{2}{s} & \frac{1}{s} \\ \frac{1}{s} & \frac{2}{s} \end{bmatrix}$$

we know, $[Y] = [Z]^{-1}$.

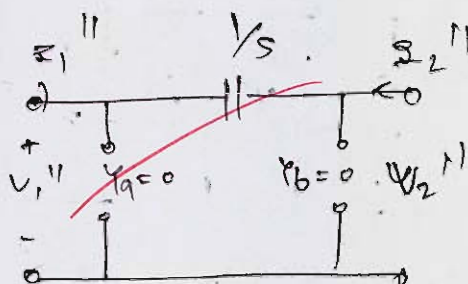
$$\therefore [Y] = \frac{1}{\Delta} \begin{bmatrix} 2/s & -1/s \\ -1/s & 2/s \end{bmatrix} \quad \text{where } \Delta = \frac{4}{s^2} - \frac{1}{s^2} = \frac{3}{s^2}$$

$$\text{where } \Delta = \frac{4}{s^2} - \frac{1}{s^2} = \frac{3}{s^2}$$

Network - 11

$$\therefore Z = \infty$$

$$\therefore Y = 0$$



$$Y_{11} = Y_a + Y_b \quad \left\{ \begin{array}{l} \text{from} \\ \text{model} \end{array} \right. \quad (\text{in Laplace domain})$$

$$Y_{12} = Y_{21} = -Y_b$$

$$Y_{22} = Y_b + Y_c$$

$$Y_{11} = 1/s$$

$$Y_{12} = Y_{21} = -1/s$$

$$Y_{22} = 1/s$$

$$\therefore [Y]_{eq} = [Y'] + [Y'']$$

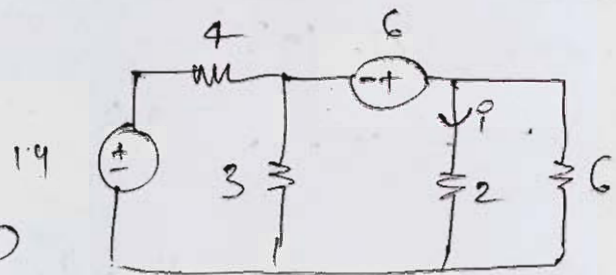
$$[Y_{eq}] = \begin{bmatrix} \frac{2s}{3} + \frac{1}{s} & -\frac{s}{3} - \frac{1}{s} \\ -\frac{s}{3} - \frac{1}{s} & \frac{2s}{3} + \frac{1}{s} \end{bmatrix}$$

$$[Y_{eq}(s)] = \begin{bmatrix} \frac{2s}{3} + \frac{1}{s} & -\left(\frac{s}{3} + \frac{1}{s}\right) \\ -\left(\frac{s}{3} + \frac{1}{s}\right) & \frac{2s}{3} + \frac{1}{s} \end{bmatrix} \quad \text{--- (1)}$$

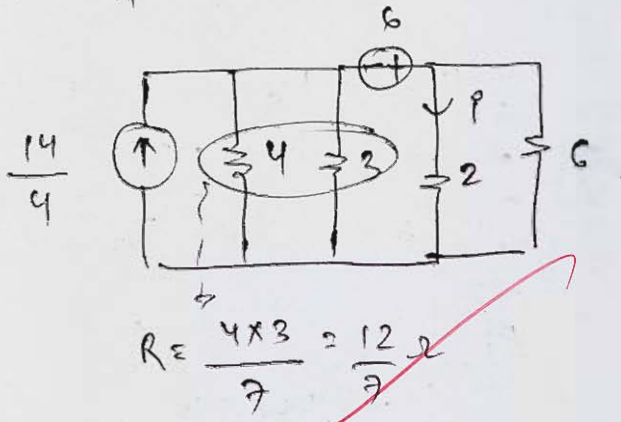
Conclusion

① Represents parameters in S-domain.

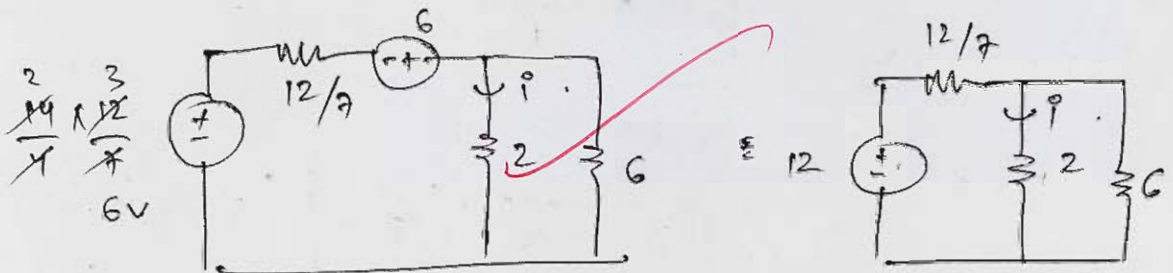
Q4) (c) (i) Given circuit



from source, step-① transformation.



∴ Repeating step-① again



By KCL, $\frac{V-12}{\frac{12}{7}} + \frac{V}{2} + \frac{V}{6} = 0$

$$V \left(\frac{7}{12} + \frac{1}{2} + \frac{1}{6} \right) = 7$$

$$V \times \frac{5}{4} = 7$$

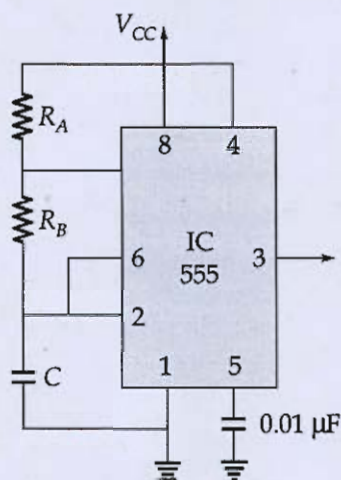
$$\therefore \boxed{V = 5.6 \text{ V}}$$

$$I = \frac{5.6}{2}$$

$$\boxed{I = 2.8 \text{ A}}$$

Section B

Q.5 (a) In the astable multivibrator shown in figure below:



where, $R_A = 2.2 \text{ k}\Omega$, $R_B = 3.9 \text{ k}\Omega$ and $C = 0.1 \text{ }\mu\text{F}$

Determine:

- Positive pulse width.
- Negative pulse width.
- Free running frequency.
- Duty cycle.

[12 marks]

Q.5 (a) Given: Astable multivibrator.

$$R_A = 2.2 \text{ k}\Omega$$

$$C = 0.1 \text{ }\mu\text{F}$$

$$R_B = 3.9 \text{ k}\Omega$$

(i) Positive pulse width

$$(\text{Charge time}) = T_c = 0.69 (R_A + R_B) C \quad \text{--- (1)}$$

equation (1) represents charging time of
Astable multivibrator.

$$T_1 = T_c = 0.69 (2.2 + 3.9) \times 0.1$$

$$\boxed{T_1 = 0.420 \text{ mSec.}}$$

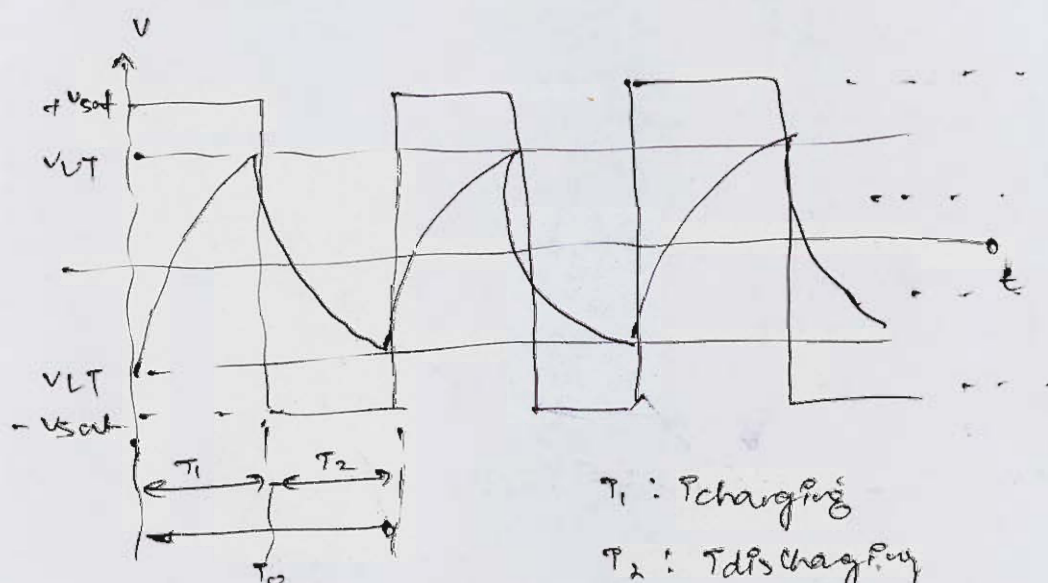
(ii) negative pulse width

(discharging time)

$$T_D = T_2 = 0.69 R_B C$$

$$T_2 = 0.69 \times 3.9 \times 0.1$$

$$T_2 = 0.269 \text{ msec}$$



T_1 : T_{charging}

T_2 : $T_{\text{discharging}}$

(iii) free running freq (f_0)

$$T_0 = T_1 + T_2 = 0.420 + 0.269$$

$$T_0 = 0.689 \text{ msec}$$

$$f_0 = \frac{1}{T_0}$$

$$f_0 = 1.451 \text{ kHz}$$

(iv) Duty cycle

$$\text{Duty cycle} = \frac{(R_A + R_B)}{(R_A + 2R_B)} \times 100$$

$$= \frac{2.2 + 3.9}{(2.2 + 2 \times 3.9)} \times 100$$

$$= \frac{6.1}{10} \times 100$$

$$\boxed{\text{duty cycle} = 61\%}$$

12

Q.5 (b) A thermistor has a resistance of $3.9 \text{ k}\Omega$ at the ice point (0°C) and 794Ω at 50°C . The resistance temperature relationship is given by,

$$R = \alpha R_0^{\beta/T}$$

where, R = resistance at temperature (T) in Kelvin,

R_0 = resistance at ice point (273 K),

α, β are constants.

- Calculate the constants α and β .
- Calculate the range of resistance measured in the case of temperature variation from 40°C - 100°C .

[12 marks]

5 (b) Given: $R = 3.9 \text{ k}\Omega$ ($T = 0^\circ\text{C}$) — (a)

$R = 794 \Omega$ ($T = 50^\circ\text{C}$) — (b)

from above, it is
(NTC) (Resistance)

Given condⁿ, $R = \alpha R_0^{\beta/T}$ — (1)

Applying above condition,

$$3.9 = \alpha \times 3.9^{\beta/273}$$

$$\alpha = \frac{3.9}{3.9^{\beta/273}} = 3.9^{(1 - \beta/273)} \quad \text{--- (2)}$$

from (1), $0.794 = \alpha \cdot 3.9^{\beta/(273+50)}$

$$0.794 = \alpha \cdot 3.9^{\beta/323} \quad (3)$$

Put (2) in (3),

$$0.794 = 3.9^{(1-\beta/273)} \times 3.9^{\beta/323}$$

$$0.794 = 3.9^{(1 - \frac{\beta}{273} + \frac{\beta}{323})}$$

$$-0.169 = 1 - \frac{\beta}{273} + \frac{\beta}{323}$$

$$-0.169 = 1 - \beta(5.67 \times 10^{-4})$$

$$\beta = \frac{1.169}{5.67 \times 10^{-4}}$$

$$\boxed{\beta = 2061.72}$$

on Solving,

$$\boxed{\alpha = 1.33 \times 10^{-4}}$$

(ii)

Resistance Range $(40^\circ\text{C} - 100^\circ\text{C})$

$$R_{40^\circ\text{C}} \Rightarrow R = \alpha R_0^{\beta/T}$$

$$R_{40^\circ\text{C}} = 1.33 \times 10^{-4} \times 3.9^{2061.72/(273+40)}$$

$$R_{100^\circ\text{C}} = 1.33 \times 10^{-4} \times 3.9^{2061.72/(273+100)}$$

on solving

$$R_{40^{\circ}\text{C}} = 1.04 \text{ k}\Omega$$

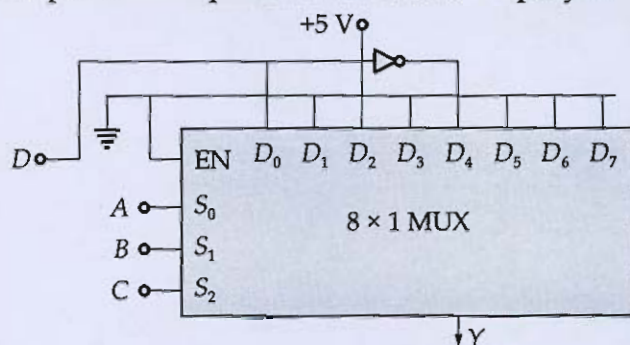
$$R_{100^{\circ}\text{C}} = 0.245 \text{ k}\Omega$$

$$\therefore \text{Range} = 1.04 - 0.245 \text{ k}\Omega$$



- 5 (c) The circuit given below shows how an 8-bit MUX can be used to generate a four-variable logic function, even though the MUX has only 3 SELECT inputs. Three of the logic variables A , B and C are connected to the SELECT inputs. The fourth variable D and its inverse $\bar{D}$ are connected to selected data inputs of the MUX as required by the desired logic function. The other MUX data inputs are tied to a LOW or a HIGH as required by the function.

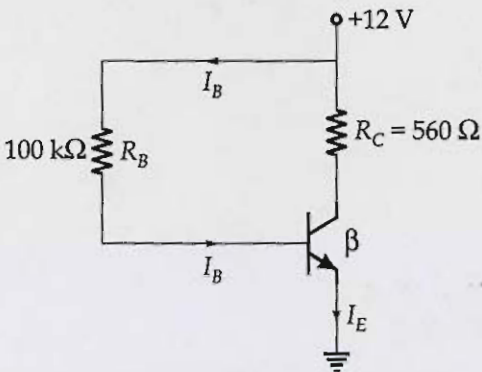
- Setup a truth table showing the output- Y for the 16 possible combinations of input variables.
- Write the sum of products expression for Y and simplify it.



[12 marks]



Q.5 (d) A base bias circuit in figure below is subjected to an increase in temperature from 25°C to 75°C. If $\beta = 100$ at 25° and 150 at 75°C, determine the percentage change in Q-point values (V_{CE} and I_C) over this temperature range.



(Neglect any change in V_{BE} and the effects of any leakage current)

[12 marks]

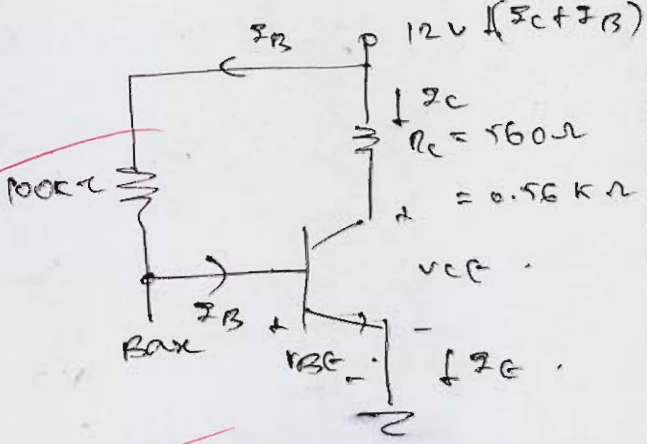
Q.5 (d) Given: Fixed bias circuit!

for $T = 25^\circ\text{C}$.
 $\beta = 100$.

By KVL in base loop,
 $-12 + 100 I_B + V_{BE} = 0$.

$$I_B = \frac{12 - 0.7}{100}$$

$$I_B = 0.113 \text{ mA}$$



(Fixed bias configuration)

$$I_c = \beta I_B$$

$$\therefore I_{c1} = 11.3 \text{ mA}$$

By KVL in collector loop,

$$-12 + I_{c1} \times R_c + V_{CE} = 0$$

$$V_{CE} = 12 - I_{c1} \times R_c$$

$$= 12 - 11.3 \times 0.56$$

$$V_{CE1} = 5.672 \text{ V}$$

Case ②) Temp = 75°

$$\beta = 150$$

$$I_B = \frac{12 - V_{BE}}{R_B} = 0.113 \text{ mA}$$

$$I_{c2} = \beta I_B$$

$$I_{c2} = 150 \times 0.113$$

$$I_{c2} = 16.95 \text{ mA}$$

By KVL in collector loop,

$$-12 + I_{c2} \times R_c + V_{CE2} = 0$$

$$V_{CE2} = 12 - I_{c2} \times R_c$$

$$= 12 - 16.95 \times 0.565$$

$$V_{CE2} = 2.423 \text{ V}$$

percentage changes

$$\% \text{ change in } I_C = \frac{I_{C2} - I_{C1}}{I_{C1}}$$

$$= \frac{16.95 - 11.3}{11.3}$$

$$I_C = 50\%$$

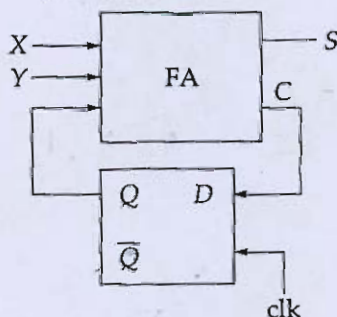
$$\% \text{ change } P_m$$

$$V_{CE} = \frac{V_{CE2} - V_{CE1}}{V_{CE1}}$$

$$= \frac{2.423 - 5.62}{5.62}$$

$$\% \text{ change } S = 57.25\%$$

- 2.5 (e) A sequential circuit has one flip-flop, two inputs X and Y, and one output S. It consists of a full adder circuit connected to a D flip-flop as shown. Derive the state table and state diagram of the given sequential circuit.



[12 marks]

(e) Given: circuit with full adder and D flip flop.

Statement: for ~~D flip flop~~, the relationship between next and present state

$$\text{is } Q^+ = D$$

Truth Table for the F.A would be :-

X	Y	Q	S	Count
0	0	0	0	0
0	0	1	1	0
0	1	0	1	0
0	1	1	0	1
1	0	0	1	0
1	0	1	0	1
1	1	0	0	0
1	1	1	1	1

Here, $Q = \text{Cf}$.

$$\& \text{Count} = D = Q^+$$

where

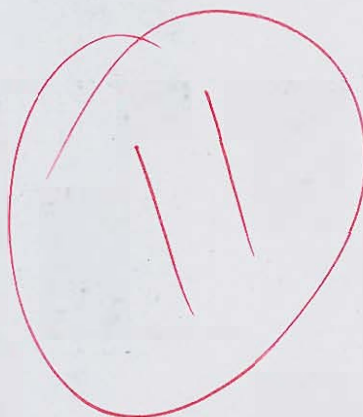
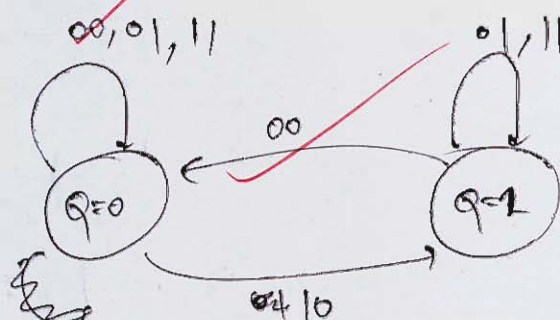
$$S = A \oplus B \oplus Q$$

$$\text{Count} = AB + BQ + QA$$

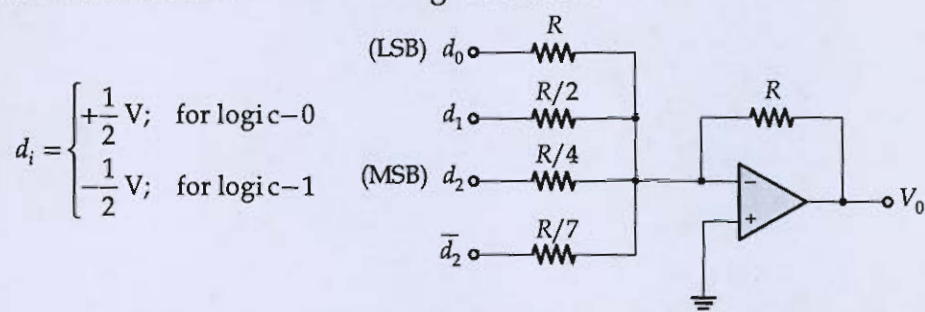
8. state table :-

Q	X	Y	Q ⁺
0	0	0	0
1	0	0	0
0	0	1	0
1	0	1	1
1	1	0	0
0	1	0	1
0	1	1	0
1	1	1	1

state diagram :-



Q.6 (a) (i) Consider the circuit shown in the figure below:



Derive an expression for output voltage V_0 in terms of input logic values. Using the result obtained, determine the value of V_0 for all the possible binary combinations of input and comment on the operation performed by the circuit.

(ii) Define the terms resolution, settling time and temperature sensitivity with respect to digital-to-analog converters.

[15 + 5 marks]

- 6 (b) In a dynamometer type wattmeter the moving coil has 500 turns of mean diameter 30 mm. Estimate the torque if the axes of the field and the moving coils are at (i) 60° (ii) 90° when the flux density produced by field coil is $15 \times 10^{-3} \text{ Wb/m}^2$, the current in moving coil is 0.05 A and the power factor is 0.866.

[20 marks]

- Q.6 (c) (i) In a silicon pn -junction, the ratio of electron current crossing the depletion region to the total current is defined as the electron injection efficiency. Determine the expression for electron injection efficiency as a function of N_a/N_d where N_a = acceptor concentration on p -side and N_d = donor concentration on n -side. Assume $T = 300\text{K}$, $\tau_{p0} = \tau_{n0}$ and $\mu_n = 2.4 \mu_p$.
- (ii) The critical magnetic field for a superconducting tin at 4 K and 3 K are 0.02T and 0.03T respectively. Calculate the critical magnetic field at 2 K.

[10 + 10 marks]

2.7 (a) (i) Draw a logic circuit for 4-bit even parity checker.

(ii) Solve for 'x' in the below equations for the given number systems:

1. $(70)_8 + (122)_6 = (211)_x$

2. $(135)_{12} = (x)_8 + (78)_9$

[14 + 6 marks]

Q.7 (b)

A star connected 3 phase alternator delivers a 3-phase star connected load at a power factor of 0.8 lagging. A wire connects the load and alternator. The terminal voltage at no load is 2500 V, and at full load of 1460 kW is 2200 V. Determine the terminal voltage when it delivers a 3 phase star connected load having a resistance of $6\ \Omega$ and reactance of $8\ \Omega$ per phase. Assume constant current and field excitation. Neglect the armature resistance.

[20 marks]

- 7 (c) Design a parallel binary multiplier that multiplies a 4-bit number $B = B_3B_2B_1B_0$ by a 3-bit number $A = A_2A_1A_0$ to form the product $P = P_6P_5P_4P_3P_2P_1P_0$.

[20 marks]

- Q.8 (a) (i) A 3 phase, 10 kW, 6 pole, 50 Hz, 400 V delta connected induction motor runs at 960 rpm on full load. If it draws 85 A on direct on line starting, calculate the ratio of the starting torque to full load torque with Y- Δ starter. Power factor and full load efficiency are 0.88 and 90% respectively.
- (ii) A 6 pole, 50 Hz, three phase induction motor has a maximum torque of 200 N-m when it is running at a speed of 900 rpm. The resistance of the rotor is 0.25 Ω . Neglecting the stator impedance, determine the torque at 5% slip.

[10 + 10 marks]

Q.8)

$$(a) \cdot 3 \phi \quad \cdot P = 6$$

$$(P) \cdot 10 \text{ kW} \quad \cdot f = 50 \text{ Hz}$$

$$N = 960 \text{ rpm.}$$

$$\eta_{fl} = 90\%$$

$$\cos \phi = 0.88$$

Q8) (a) (i) $p = 6$. 3ϕ .

$f = 50 \text{ Hz}$. $T_{\max} = 200 \text{ N-m}$. $N_{\max} = 900 \text{ rpm}$.

$R = 0.25 \Omega$.

$S = 5\% = 0.05$.

statement: we know,

$$\frac{T}{T_{\max}} = \frac{2}{\frac{S}{S_{\max}} + \frac{S_{\max}}{S}}$$

$$N_s = \frac{120f}{p} = \frac{120 \times 50}{6} = 1000 \text{ rpm} .$$

$$S_{\max} = \frac{1000 - 900}{1000} = 0.1$$

$$\therefore \frac{T}{T_{\max}} = \frac{2}{\frac{0.05}{0.1} + \frac{0.1}{0.05}} = \frac{2}{0.5 + 2}$$

$$\frac{T}{T_{\max}} = \frac{4}{5}$$

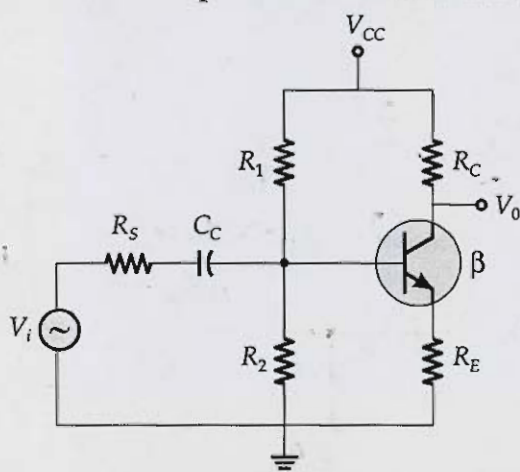
$$T = \frac{4}{5} T_{\max}$$

$$T = 160 \text{ N-m}$$

$\therefore$ At 5% slip, the Torque is 160 N-m .

10

Q.8 (b) Consider the common emitter amplifier as shown in the figure below:



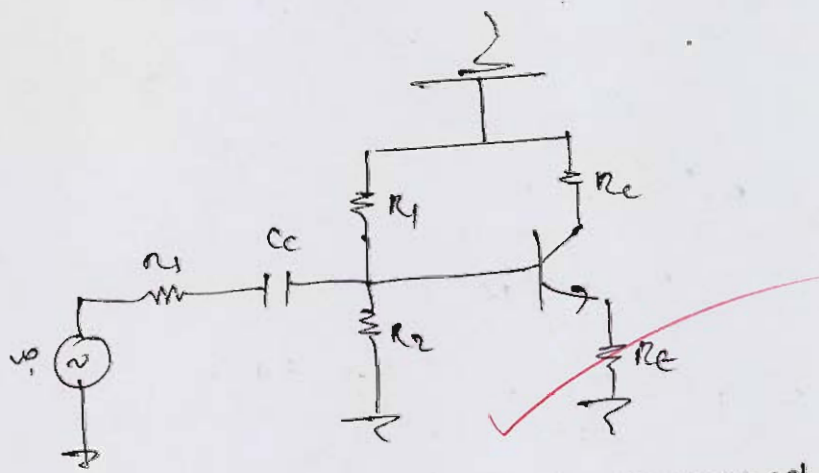
Derive the expression for the overall voltage gain of the transistor $A_V(s)$ as a function of input capacitance C_C . Also draw the approximate magnitude plot for the voltage gain $A_V(s)$. [Assume $V_A = \infty$]

[20 marks]

8 (b) Given: CE amplifier without bypass capacitor:

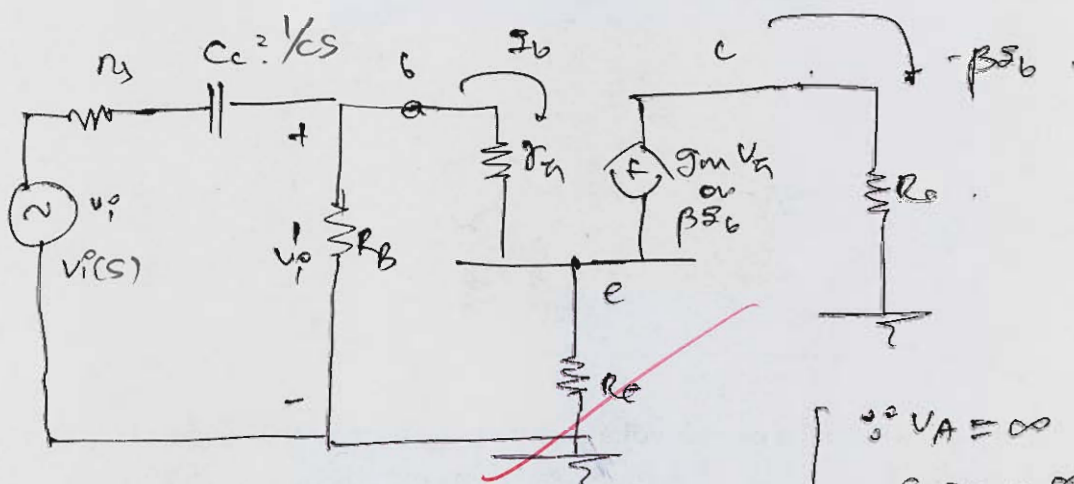
Statement: for amplifier analysis, considering medium frequency AC equivalent circuit.

• voltage sources are short circuited.



(Blocking capacitor is not removed for calculation purposes).

from (ii) model :-



$$R_B = R_1 || R_2$$

$$\left[\begin{array}{l} \omega \rightarrow \infty \quad V_A = \infty \\ \omega \rightarrow 0 \quad \tau_o = \infty \end{array} \right]$$

π -model of the circuit.

voltage gain. $A_v'(s) = \frac{-\beta \beta_b R_c}{r_{\pi} \tau_{\pi} + (1+\beta) \beta_b R_c} \cdot \frac{v_o}{v_i'}$

$$\left\{ A_v'(s) = \frac{-\beta R_c}{r_{\pi} + (1+\beta) R_e} \right\}$$

$$A_v(s) = \frac{A_v'(s) \times R_B}{R_B + Z_{in}}$$

where

$$Z_{in} = R_s + \frac{1}{Cs} = \frac{R_s Cs + 1}{Cs}$$

$$A_v(s) = \frac{-\beta R_c R_B}{(r_{\pi} + (1+\beta) R_e) [R_B + Z_{in}]}$$

$$A_{v(s)} = \frac{-\beta R_e R_B}{(r_n + (1+\beta)R_e) \left(R_B + \frac{R_s(s+1)}{C_s} \right)}$$

$$A_{v(s)} = \frac{-\beta R_e R_B \times C_s}{[r_n + (1+\beta)R_e] [R_B C_s + R_s C_s + 1]}$$

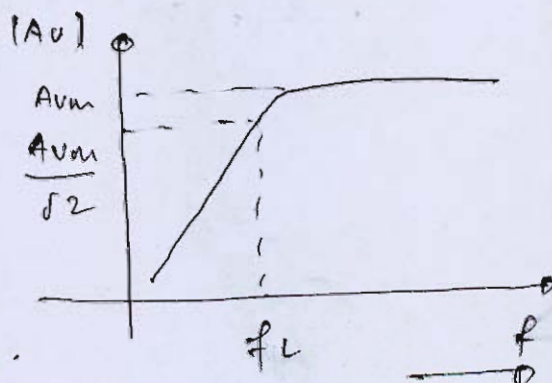
①

① represents gain with considering of the blocking capacitor.

The voltage gain decreases at low frequencies, because of the effect of the capacitance.

$$A_{vL} = \frac{A_{vm}}{1 - j \frac{f_L}{f}}$$

$$A_{v(s)} = \frac{-\beta R_e R_B}{r_n + (1+\beta)R_e} \cdot \frac{1}{\left(\frac{1 + (R_B + R_s)C_s}{C_s} \right)}$$



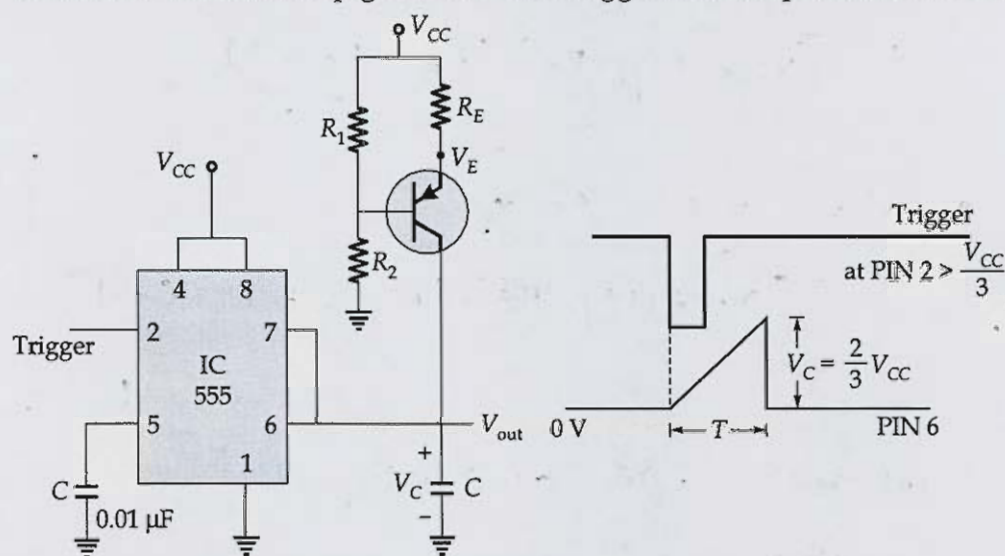
$$A_{v(s)} \approx \frac{A_{vm}}{1 - j \frac{f_L}{f}}$$

$$f_L = \frac{1}{2\pi (R_B + R_s) C_s}$$

where, $f_L = \frac{1}{2\pi (R_B + R_s) C_s}$

18

Q.8 (c) Consider the linear ramp generator with trigger and ramp waveform as shown below:



Determine the time period (T) of ramp waveform.

[20 marks]

Q8) (c) we know,

Capacitor equation:-

$$V_C(t) = (V_C(0^+) - V_C(\infty))e^{-t/\tau} + V_C(\infty)$$



(conv) (Diff)

B

Space for Rough Work

difference

A B C P_n

0	0	0	0	0
0	0	1	1	1
0	1	0	1	1
0	1	1	1	0
1	0	0	0	1
1	0	1	0	0
1	1	0	0	0
1	1	1	1	1

1, 2, 4, 7

	BC	00	01	11	10
A	0	0	1	3	1
	1	1	1	2	6

$\Sigma A \oplus B \oplus C P_n$

Σe

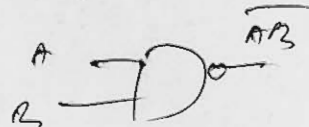
$\Sigma(46) \Sigma n$

$\Sigma 46 \Sigma n$

$$Y = D + AB + BC$$

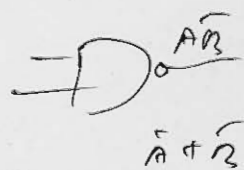
$$Y = D + AB + BC$$

$$= \overline{D} \cdot \overline{AB} \cdot \overline{BC}$$



$$= \overline{D} + \overline{AB}$$

(POS)



$$= \overline{D} + \overline{AB} + \overline{BC}$$

$$D = \frac{\frac{2}{5}}{\frac{3}{5^2}} = \frac{2 \times 5^2}{3 \times 5} = \frac{2 \times 5}{3}$$

$$= \frac{1 \times 5^2}{5 \times 3}$$

Space for Rough Work
